

# Comprehensive power delivery solution for modern AI data centers

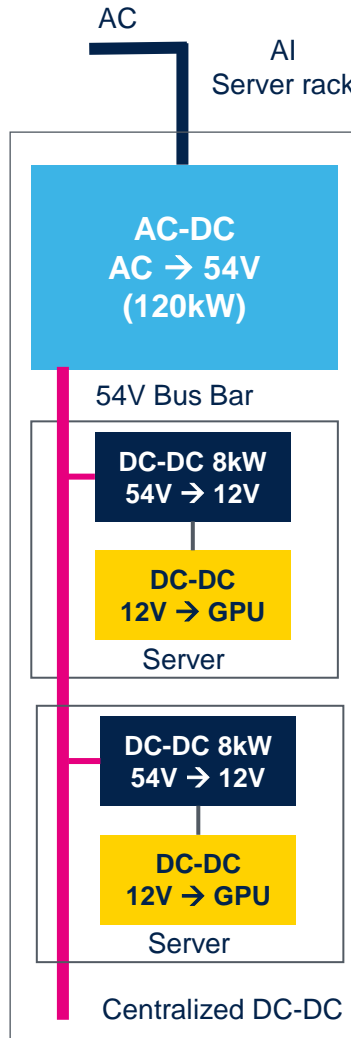
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STMicroelectronics

# Comprehensive Power Delivery for Modern Data Centers

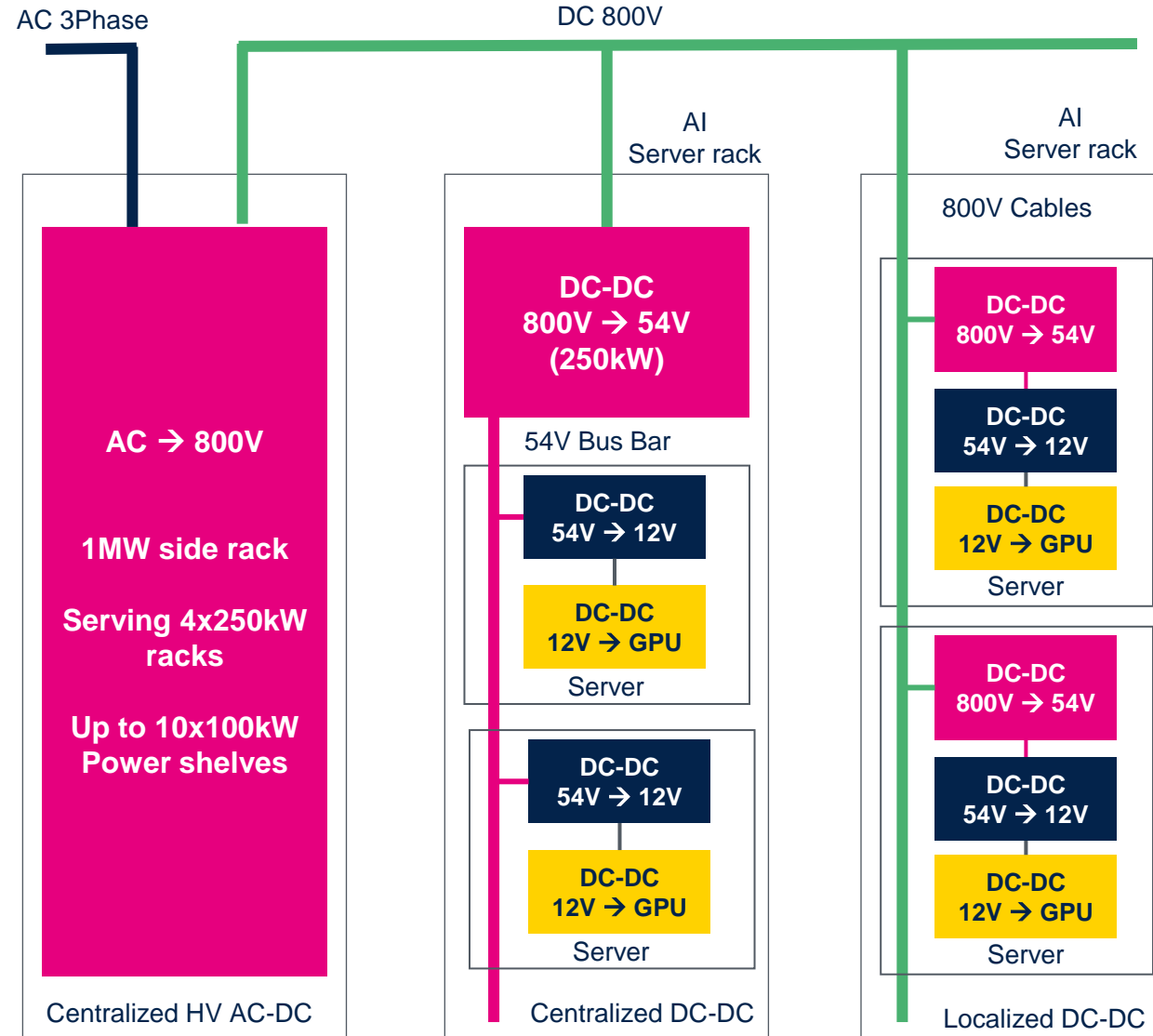
1. Modern AI Data Center Infrastructure
2. ST Power Deliver from Grid to POL
3. 30kW 3-phase Vienna rectifier
4. 30kW 3-phase LLC converter
5. 1kW GaN-based converter
6. 32 phase xPU VR with dual-phase power block



# 800V rack power delivery



Today

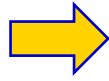




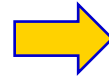
# Comprehensive ecosystem

## From three phase AC to xPU POL

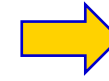
3 phase AC  
to  
400V/800V



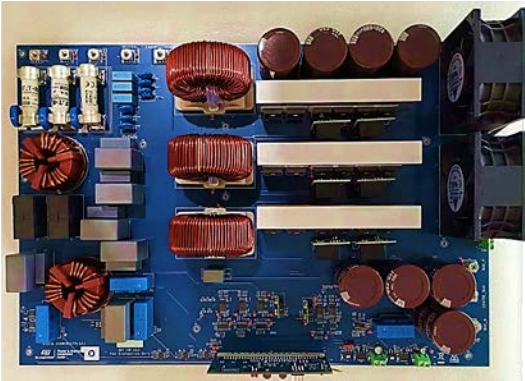
400V/800V  
to  
54V



IBC  
54V to 12V



POL VR  
12V to xPU



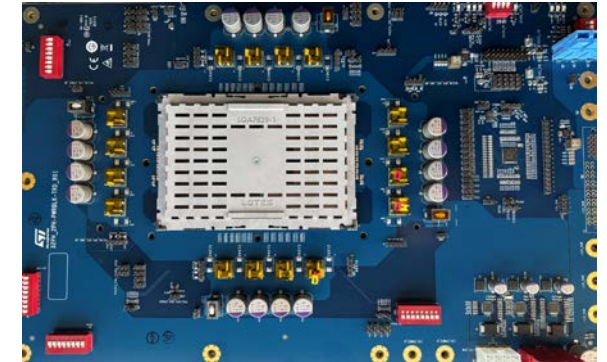
30kW 3-phase Vienna  
rectifier



30kW 3-phase  
LLC converter



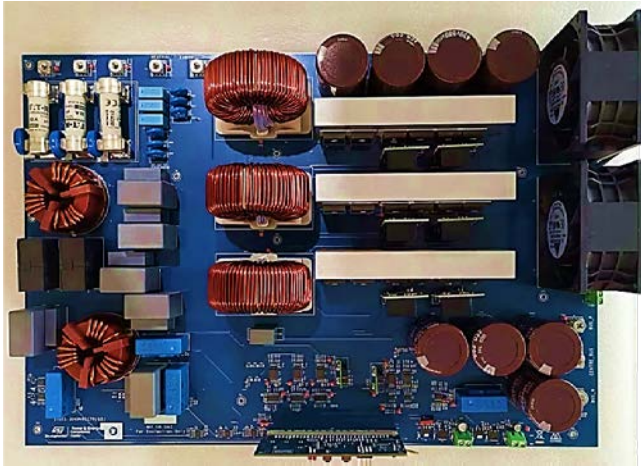
1kW GaN-based  
converter



32 phase xPU VR  
with dual-phase  
power block

# **30 kW three-phase Vienna rectifier**

# 30 kW three-phase Vienna rectifier



## Application key specification

1. Input AC voltage: three-phase 345 VAC up to 460 VAC with 47 Hz up to 63 Hz
2. Maximum input current: 55 ARMS
3. DC Vout 800 VDC, rated output power **30 kW**, switching frequency 70 kHz
4. Peak efficiency **>98.7%**
5. 0.99 power factor with lower than 5% THD @ full load operation
6. STM32G474: high performance 32-bit MCU

## Key products

1. MCU: STM32G474RET3
2. SiC MOSFET: SCT018W65G3-4AG
3. SiC diode: STPSC40H12C
4. Gate driver: STGAP2SICS
5. Schottky diodes: STTH1L06A, STPS1150A, STPS2H100A, STPS2L60A
6. GPA: LD29080S33R, LD29080DT50R, TSV912IDT, TSV912IDT

## Key benefits

- Solution based on SiC device; higher efficiency achieved
- Very low THD (total harmonic distortion)
- **Higher reliability**
- Low design complexity

# 30 kW three-phase LLC converter

# 30 kW three-phase LLC converter



## Application key specification

1. Rated output power: 30 kW, switching frequency 100-300 kHz
2. DC input voltage: 650 VDC – 850 VDC
3. DC output: 200 VDC – 1000 VDC
4. Peak efficiency >98%
5. STM32G474: high performance 32-bit MCU

## Key products

1. MCU: STM32G474VET6,
2. SiC MOSFET: SCT025W120G3-4AG
3. Ultrafast diode: STTH60RQ06W
4. ASP product: STGAP2SICS, L6565
5. Schottky diodes: STTH1L06A, STPS1150A, STPS2H100A, STPS2L60A
6. GPA: LM393DT, LD29080DT50R, LD29080DT33R, TSV9121DT

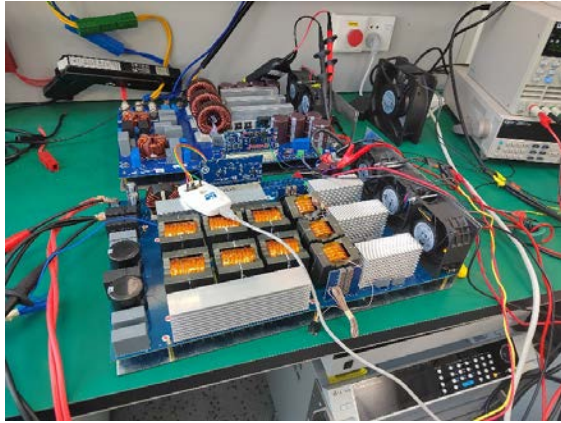


## Key benefits

1. Higher efficiency with **1200V** SiC device and high switching frequency
2. Less SiC MOSFET to achieve higher power with single LLC converter
3. Wide range and high output voltage



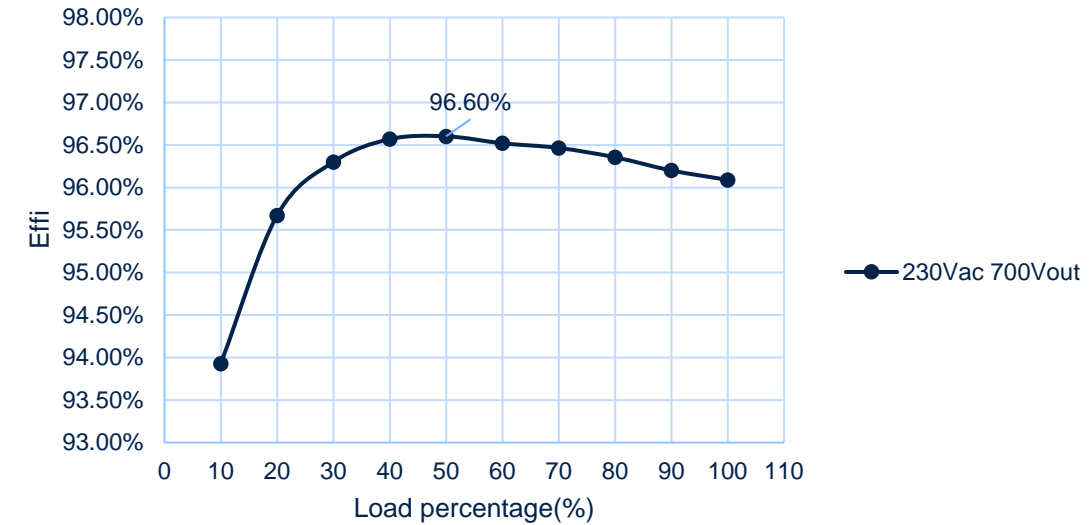
# ST 30 kW total solution



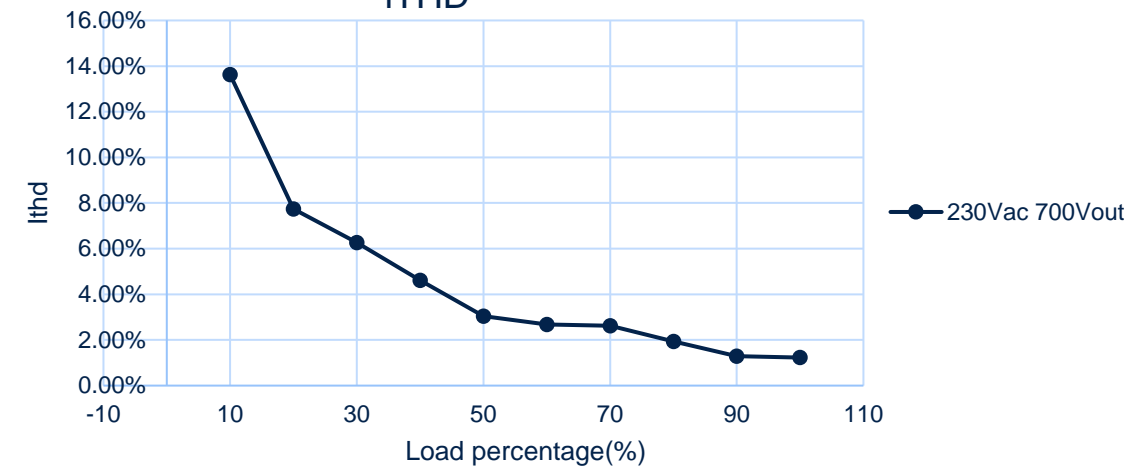
96.6% peak and 96% high efficiency in full load



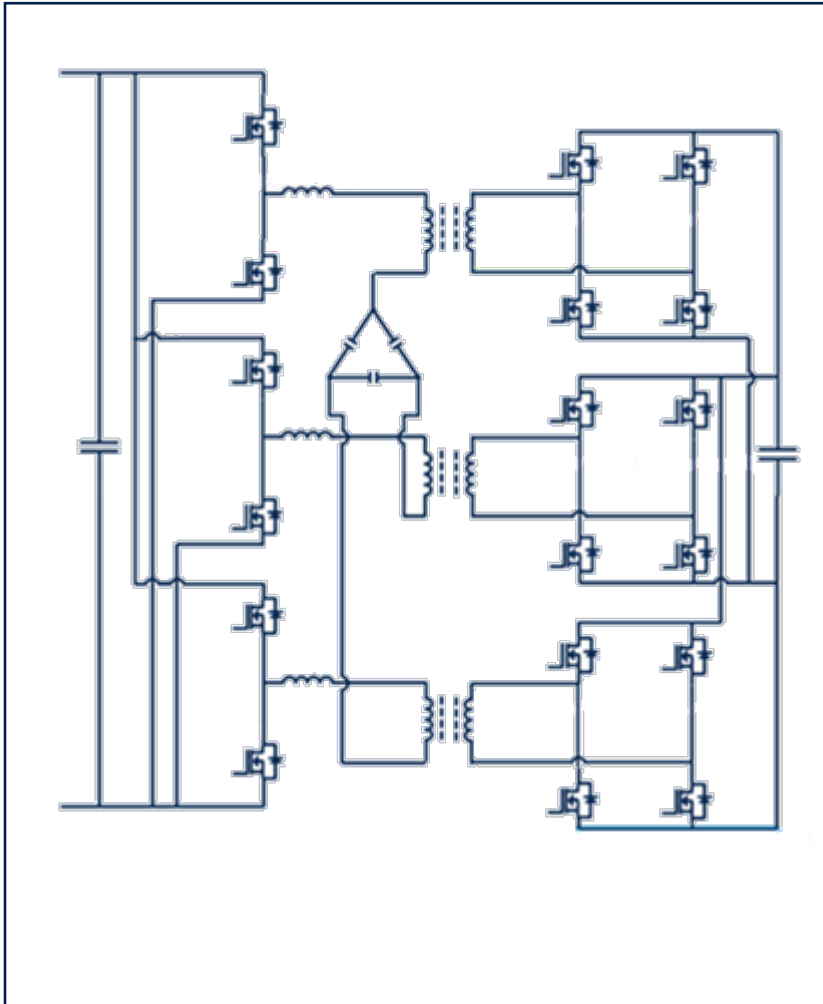
Efficiency



iTHD



# 800V to 54V three-phase LLC converter



## Application key specification

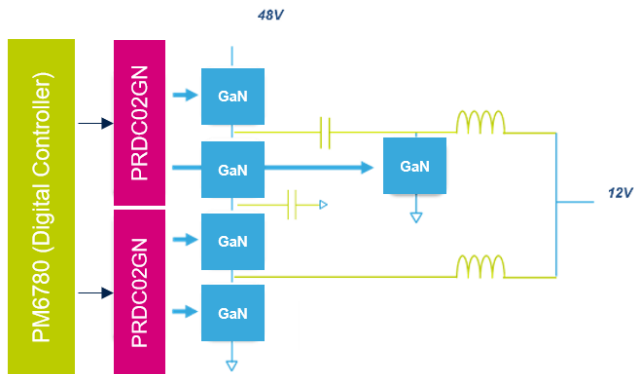
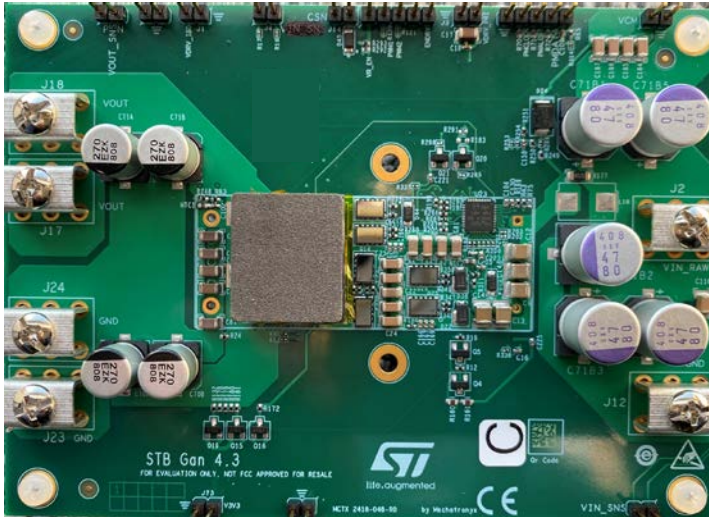
1. Rated output power: **10 kW**, switching frequency **100-300 kHz**
2. DC input voltage: 750V-850 VDC
3. DC output: 54 VDC
4. Peak efficiency: **>98%**
5. STM32G474: High performance 32-bit MCU

## Key benefits

1. Higher efficiency with **1200V SiC** and high switching frequency
2. Less SiC MOSFET for higher power single LLC converter
3. High power density

# 1kW GaN-based converter

# 1kW GaN-based converter



## Application key specification

1. Intermediate bus conversion
2. High efficiency, high density regulated DC-DC in 1/8<sup>th</sup> brick FF
3. Frequency up to **800kHz** and **>98%** efficiency
4. 1kW cell scalable up to **8kW** TDP
5. Server PDB (Power Distribution Board)
6. Redundant interleaved power delivery

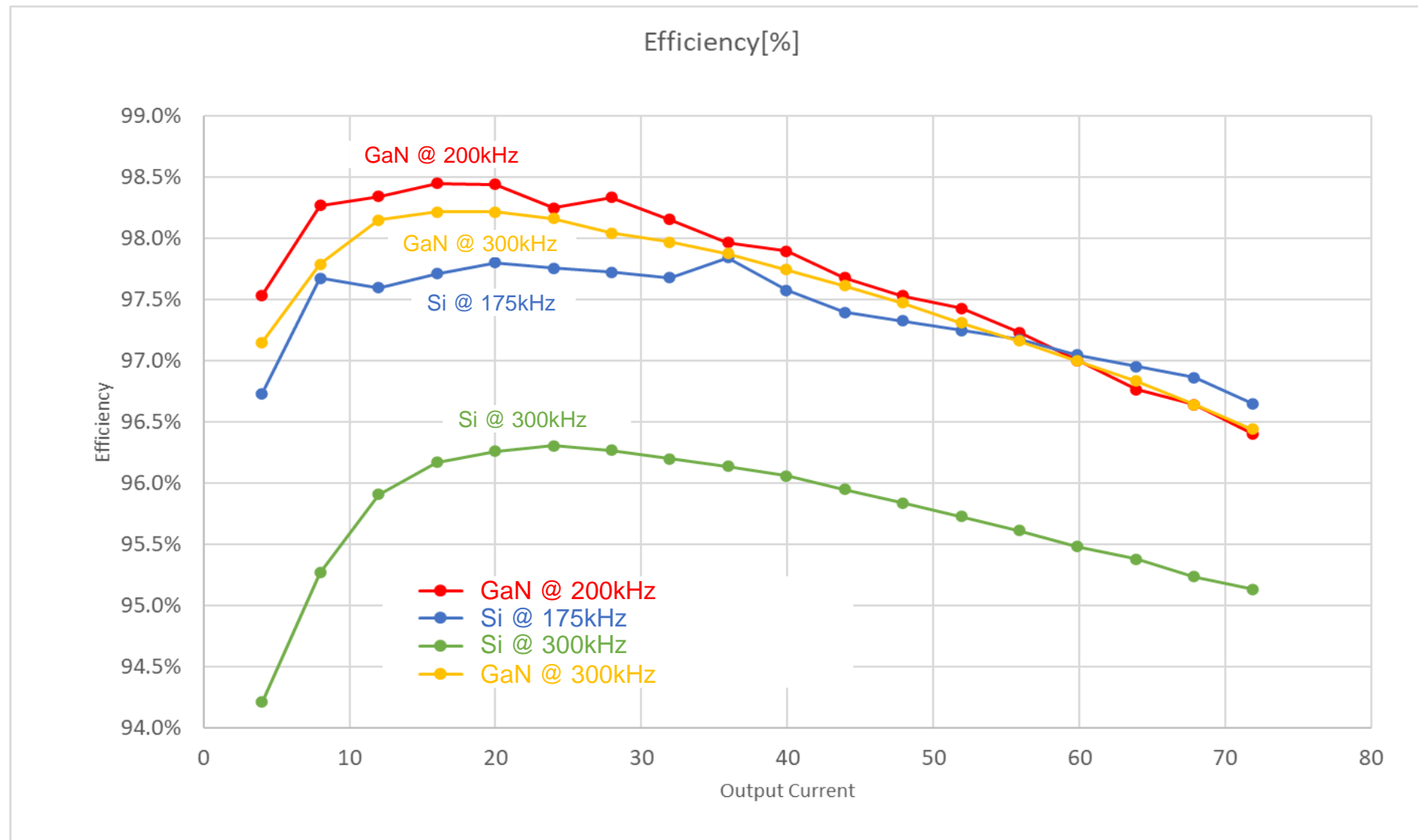
## Key products

1. Fully digital multiphase controller: PM6780
2. STPRDC02GN dual half bridge smart driver for GaN
3. 48V, 28A power eFuse: STEF48H28
4. High frequency optimized magnetic from ITG

## Key benefits

1. Higher efficiency and high density based on 100V GaN
2. Power density more than **500W/inch<sup>2</sup>**
3. High switching frequency 800kHz
4. Peak efficiency **>98%** with **flat** efficiency curve

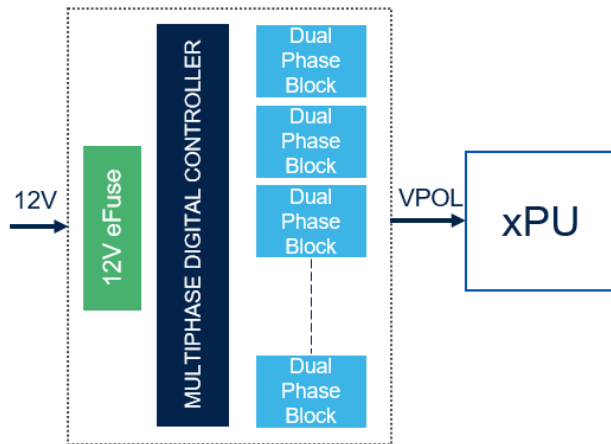
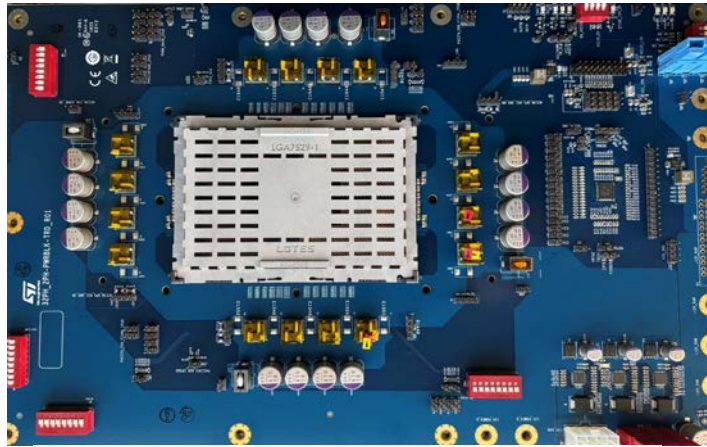
# Efficiency comparison Si MOSFET vs GaN





**32 phase xPU VR with dual-phase power block**

# 32 phase xPU VR with dual-phase power block



## Application key specification

1. Fully digital controller with 100MHz ARM Cortex uC
2. Real fully digital **STVCoT** control loop – **TLVR** supported
3. Programmable N+M phase: 16+0/8+8 --- 12+0/6+6
4. Intel VR1x.Cloud, AMD SVI3.0, AVS
5. Traditional/TLVR multiphase with **Secure PMBus™** (rev1.5)
6. Full set of protection (OV, UV, OP, OT, OC, per-phase OC)

## Key products

1. Fully digital multiphase controller for Intel, AMD and AVS: PM6784
2. Dual phase power block with 4x6 90A SPS PM7091A
3. 12V, 60A power eFuse: STEF12H60

## Key benefits

1. Flat efficiency with a peak of **93.2%**
2. 80A TDC, 140A peak **Dual Phase Power Block**
3. Firmware and configuration file upgradeable with configurable telemetry
4. Life-time counter and accurate black box recorder
5. Power stage and Lout Soldering Detection Algorithm (TLVR compatible)
6. Limp mode operations

# Efficiency at SPS with DPM enabled



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